

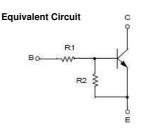
# FJY3005R **NPN Epitaxial Silicon Transistor**

# **Features**

- · Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R1=4.7KΩ, R2=10KΩ)
- Complement to FJY4005R







July 2007

# Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current	100	mA
T <sub>STG</sub>	Storage Temperature Range	-55~150	°C
TJ	Junction Temperature	150	°C
P <sub>C</sub>	Collector Power Dissipation, by $R_{\theta JA}$	200	mW

These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

## Thermal Characteristics\* Ta=25°C unless otherwise noted

Symbol	Parameter	Мах	Units
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	600	°C/W

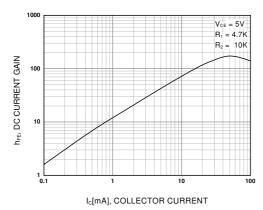
Minimum land pad size.

# Electrical Characteristics\* T<sub>c</sub> = 25°C unless otherwise noted

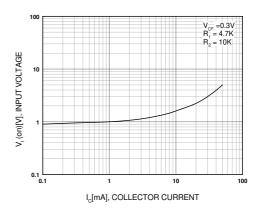
Symbol	Parameter	Test Condition	MIN	Тур	MAX	Units
V(BR)CBO	Collector-Emitter Breakdown Voltage	Ic = 10 uA, IE = 0	50			V
$V_{(BR)CEO}$	Collector-Base Breakdown Voltage	Ic = 100 uA, I <sub>B</sub> = 0	50			V
Ісво	Collector-Cutoff Current	$V_{CB} = 40 V, I_E = 0$			0.1	uA
hfe	DC Current Gain	Vce = 5 V, Ic = 5 mA	30			
VCE(sat)	Collector-Emitter Saturation Voltage	Ic = 10 mA, I <sub>B</sub> = 0.5 mA			0.3	V
f⊤	Current Gain - Bandwidth Product	Vce = 10V, Ic = 5 mA		250		MHz
Ccb	Output Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz		3.7		pF
VI(off)	Input Off Voltage	Vce = 5 V, Ic = 100uA	0.3			V
VI(on)	Input On Voltage	Vce = 0.3V, Ic = 20mA			2.5	V
R1	Input Resistor		3.2	4.7	6.2	KΩ
R1/R2	Resistor Ratio		0.42	0.47	0.52	

# **Typical Performance Characteristics**

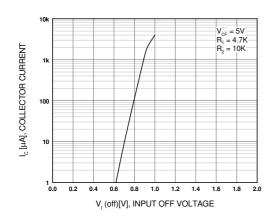
## Figure 1. DC current Gain



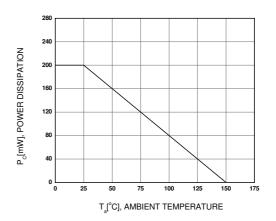
## Figure 2. Input On Voltage

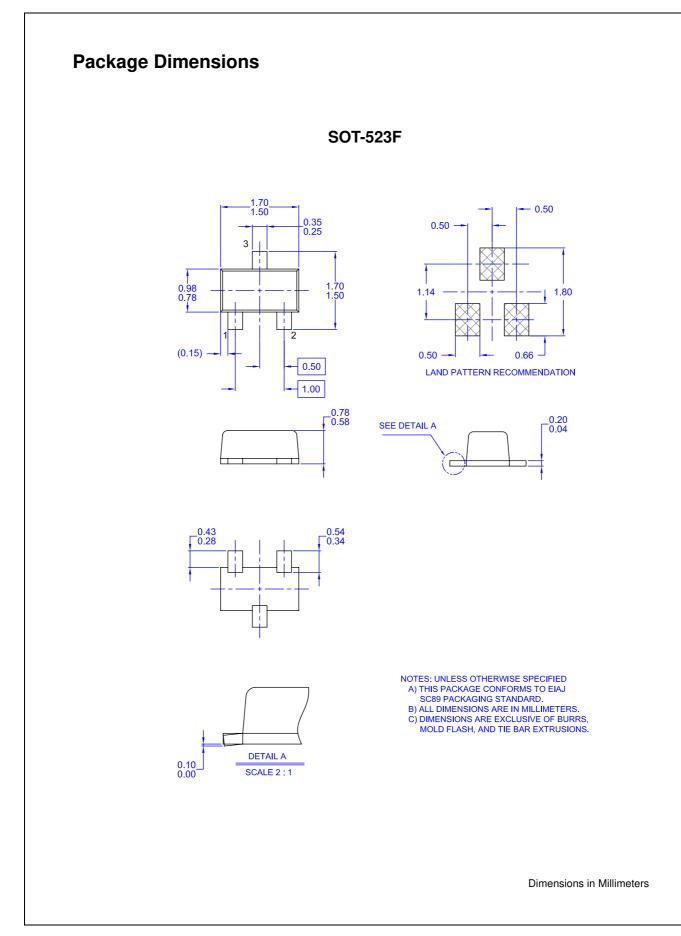


## Figure 3. Input off Voltage



#### Figure 4. Power Derating





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